

# isc P-Channel MOSFET Transistor

# DMP6180SK3-13

### • FEATURES

- Static drain-source on-resistance:
  R<sub>D</sub>s(on) ≤ 110m Ω (@V<sub>SS</sub>= -10V; I<sub>D</sub>= -12A)
- Advanced trench process technology
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



### APPLICATIONS

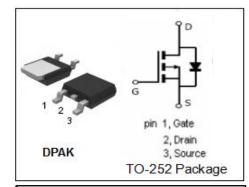
- Power Management Functions
- DC / DC Converters

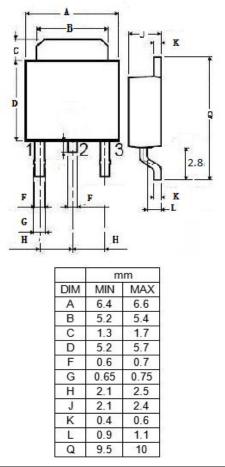


SYMBOL	PARAMETER	VALUE	UNIT	
$V_{\text{DSS}}$	Drain-Source Voltage	-60	V	
V <sub>GS</sub>	Gate-Source Voltage	±20	V	
I <sub>D</sub>	Drain Current-Continuous	-14	А	
$P_D$	Total Dissipation @T <sub>C</sub> =25℃	40	W	
Tj	Max. Operating Junction Temperature	150	°C	
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$	

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(j-c)	Channel-to-case thermal resistance	3.13	°C/W







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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = -250 μ A	-60		V
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> = -250 μ A	-1.2	-2.7	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = -10V; I <sub>D</sub> = -12A		110	$m\Omega$
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V; V <sub>DS</sub> = 0V		±100	nA
IDSS	Drain-Source Leakage Current	V <sub>DS</sub> = -48V; V <sub>GS</sub> = 0V		-1	μ <b>А</b>
$V_{SD}$	Diode forward voltage	$I_{S}$ = -1A, $V_{GS}$ = 0V		-1.0	V



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